NSN 5961-01-357-9640

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-357-9640 **Inclosure Material:** Plastic or ceramic **Overall Length:** 1.000 inches **Overall Height:** 0.250 inches **Overall Width:** 0.750 inches **Component Name And Quantity:** 6 semiconductor device diode **Mounting Method: Terminal Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 75.0 breakdown voltage, instantaneous all semiconductor device diode and 50.0 working peak reverse voltage all semiconductor device diode **Current Rating Per Characteristic:** 200.00 milliamperes forward current, average absolute all semiconductor device diode and 0.50 amperes forward current, average preset all semiconductor device diode **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No